



STPS15L30CDJF

Low drop power Schottky rectifier

Features

- Very small conduction losses
- Negligible switching losses
- Extremely fast switching
- Low forward voltage drop
- Low thermal resistance
- High avalanche capability specified
- ECOPACK[®]2 compliant component

Description

Dual center tap Schottky rectifier suited for switch mode power supply and high frequency DC to DC converters.

Packaged in Power QFN, this device is intended for use in low voltage, high frequency inverters, free-wheeling and polarity protection applications.

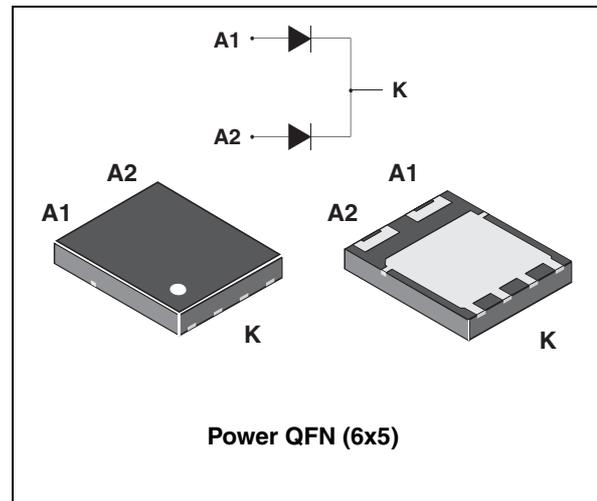


Table 1. Device summary

$I_{F(AV)}$	2 x 7.5 A
V_{RRM}	30 V
T_j (max)	150 °C
V_F (max)	0.39 V

1 Characteristics

Table 2. Absolute ratings (limiting values, per diode)

Symbol	Parameter		Value	Unit	
V_{RRM}	Repetitive peak reverse voltage		30	V	
$I_{F(RMS)}$	RMS forward current		10	A	
$I_{F(AV)}$	Average forward current	$T_c = 140\text{ °C}$	Per diode	7.5	A
		$\delta = 0.5$	Per device	15	
I_{FSM}	Surge non repetitive forward current	$t_p = 10\text{ ms}$ sinusoidal	75	A	
I_{RRM}	Peak repetitive reverse current	$t_p = 2\text{ }\mu\text{s}$ square $F = 1\text{ kHz}$	1	A	
P_{ARM}	Repetitive peak avalanche power	$t_p = 1\text{ }\mu\text{s}$ $T_j = 25\text{ °C}$	2800	W	
T_{stg}	Storage temperature range		-65 to + 175	°C	
T_j	Maximum operating junction temperature ⁽¹⁾		150	°C	

1. $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal resistance

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	Junction to case	Per diode	2.5	°C/W
		Total	1.7	
$R_{th(c)}$	Coupling		0.7	

When the diodes 1 and 2 are used simultaneously :

$$\Delta T_j(\text{diode } 1) = P(\text{diode } 1) \times R_{th(j-c)}(\text{Per diode}) + P(\text{diode } 2) \times R_{th(c)}$$

Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
$I_R^{(1)}$	Reverse leakage current	$T_j = 25\text{ °C}$	$V_R = V_{RRM}$	-	-	1	mA
		$T_j = 125\text{ °C}$		-	70	140	mA
$V_F^{(1)}$	Forward voltage drop	$T_j = 25\text{ °C}$	$I_F = 7.5\text{ A}$	-	-	0.48	V
		$T_j = 125\text{ °C}$	$I_F = 7.5\text{ A}$	-	0.34	0.39	
		$T_j = 25\text{ °C}$	$I_F = 15\text{ A}$	-	-	0.57	
		$T_j = 125\text{ °C}$	$I_F = 15\text{ A}$	-	0.44	0.51	

1. Pulse test: $t_p = 380\text{ }\mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 0.27 \times I_{F(AV)} + 0.016 I_{F(RMS)}^2$$

Figure 1. Average forward power dissipation versus average forward current (per diode)

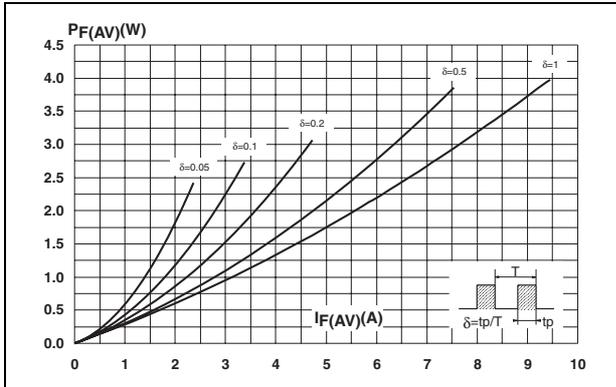


Figure 2. Average forward current versus ambient temperature ($\delta = 0.5$, per diode)

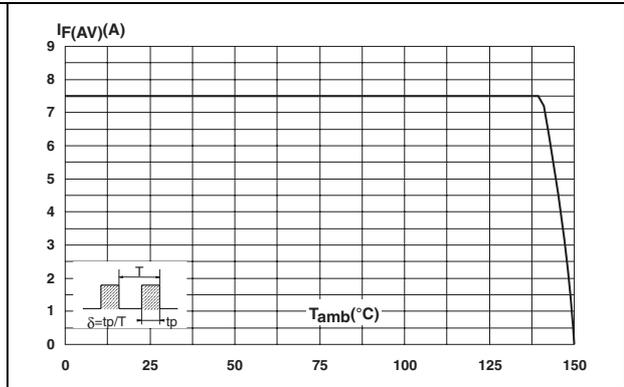


Figure 3. Normalized avalanche power derating versus pulse duration

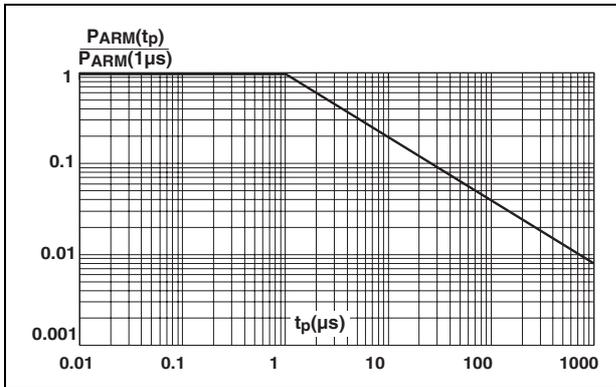


Figure 4. Normalized avalanche power derating versus junction temperature

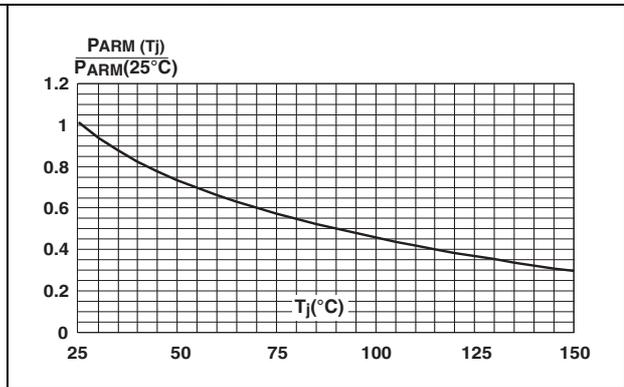


Figure 5. Non repetitive surge peak forward current versus overload duration (maximum values, per diode)

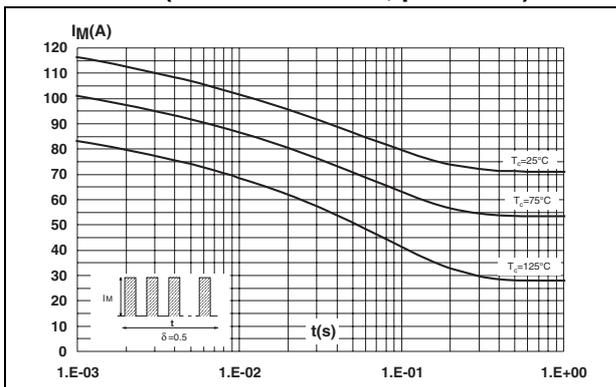


Figure 6. Relative variation of thermal impedance, junction to case, versus pulse duration

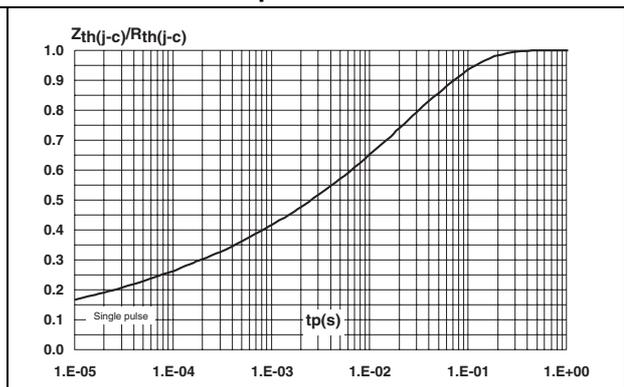


Figure 7. Reverse leakage current versus reverse voltage applied (typical values, per diode)

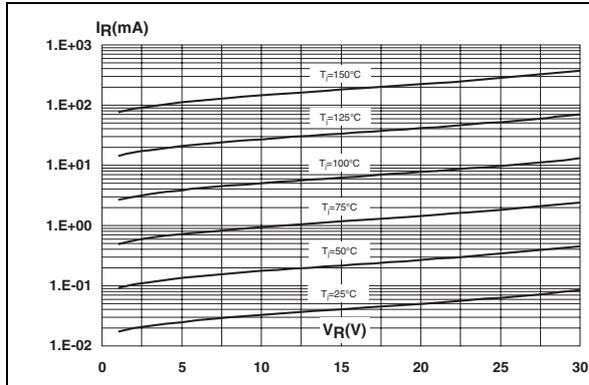


Figure 8. Junction capacitance versus reverse voltage applied (typical values, per diode)

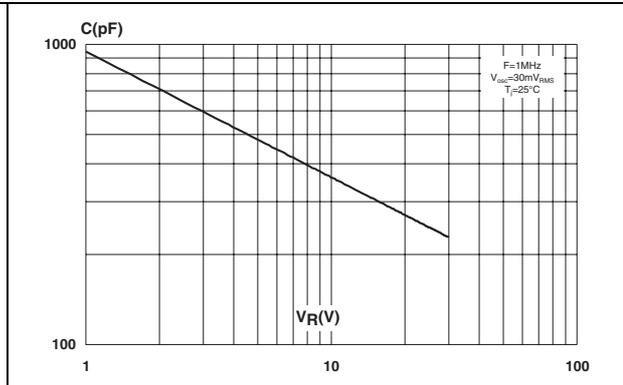


Figure 9. Forward voltage drop versus forward current

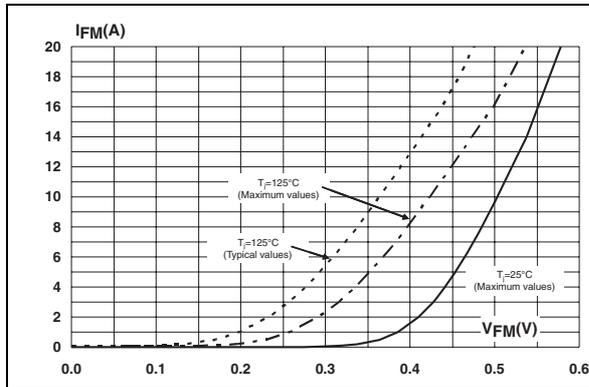
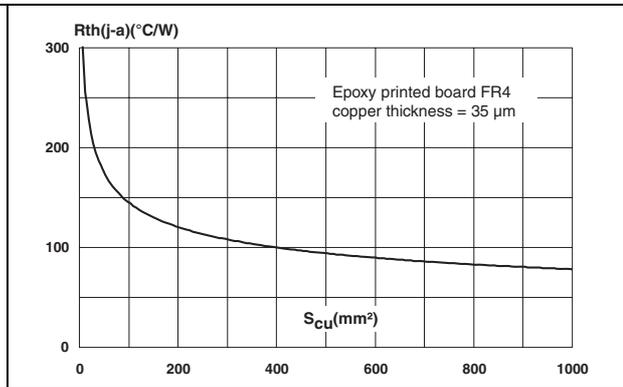


Figure 10. Thermal resistance junction to ambient versus copper surface under each lead



2 Package information

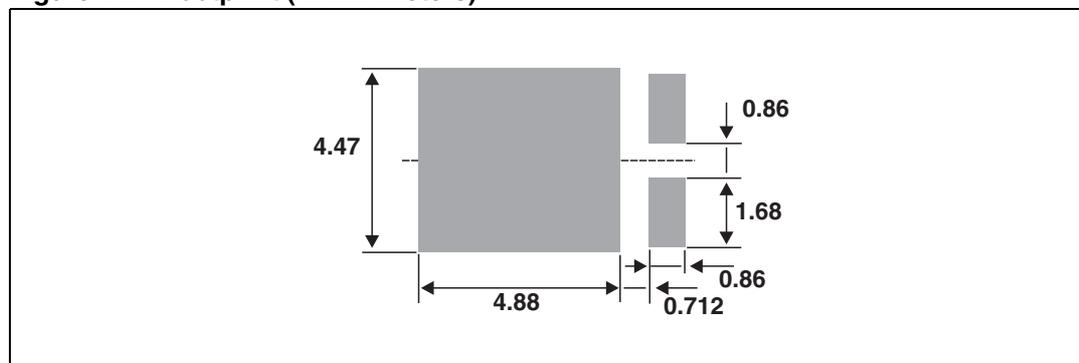
- Epoxy meets UL94,V0

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

Table 5. Package dimensions

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.95	5.05	0.195	0.199
B	5.95	6.05	0.234	0.238
C	4.58	4.68	0.180	0.184
D	4.37	4.47	0.172	0.176
D1	0.95	1.05	0.037	0.041
F	Chamfer 0.30 x 45° typ.		Chamfer 0.012 x 45° typ.	
G	1.68 typ.		0.066 typ.	
H	0.41 typ.		0.016 typ.	
J	0.59	0.63	0.022	0.026
K	0.86 typ.		0.034 typ.	
L	0.20 typ.		0.008 typ.	
M	0.41 typ.		0.016 typ.	
N	0.20 typ.		0.008 typ.	
P	0.25 typ.		0.01 typ.	
Q	0.71	0.81	0.028	0.032

Figure 11. Footprint (in millimeters)



3 Ordering Information

Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS15L30CDJF-TR	STPS15L30CDJF	Power QFN (6x5) ECOPACK [®] 2	0.095 g	5000	Tape and reel

4 Revision history

Table 7. Document revision history

Date	Revision	Changes
13-May-2009	1	First issue.

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